TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT process)

# 2SA1163

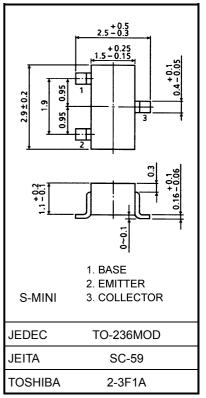
Audio Frequency General Purpose Amplifier Applications

Unit: mm

- High voltage:  $V_{CEO} = -120 \text{ V}$
- Excellent hFE linearity: hFE (IC = -0.1 mA)/hFE (IC = -2 mA) = 0.95 (typ.)
- High  $h_{FE}$ :  $h_{FE} = 200 \sim 700$
- Low noise: NF = 1dB (typ.), 10dB (max)
- Complementary to 2SC2713
- Small package

#### Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit	
Collector-base voltage	V <sub>CBO</sub>	-120	V	
Collector-emitter voltage	V <sub>CEO</sub>	-120	V	
Emitter-base voltage	V <sub>EBO</sub>	-5	V	
Collector current	Ι <sub>C</sub>	-100	mA	
Base current	Ι <sub>Β</sub>	-20	mA	
Collector power dissipation	P <sub>C</sub>	150	mW	
Junction temperature	Tj	125	°C	
Storage temperature range	T <sub>stg</sub>	-55~125	°C	



Weight: 0.012 g (typ.)

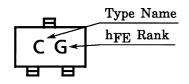
## Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I <sub>CBO</sub>	$V_{CB} = -120 V, I_E = 0$		_	-0.1	μA
Emitter cut-off current	I <sub>EBO</sub>	$V_{EB} = -5 \text{ V}, \text{ I}_{C} = 0$			-0.1	μA
DC current gain	h <sub>FE</sub> (Note)	$V_{CE} = -6 \text{ V}, \text{ I}_{C} = -2 \text{ mA}$	200		700	
Collector-emitter saturation voltage	V <sub>CE (sat)</sub>	$I_C = -10$ mA, $I_B = -1$ mA	_	_	-0.3	V
Transition frequency	f <sub>T</sub>	$V_{CE} = -6 V, I_C = -1 mA$	_	100	_	MHz
Collector output capacitance	C <sub>ob</sub>	$V_{CB} = -10 \text{ V}, \text{ I}_{E} = 0, \text{ f} = 1 \text{ MHz}$	_	4	_	pF
Noise figure	NF	$V_{CE}$ = –6 V, $I_C$ = –0.1 mA, f = 1 kHz, Rg = 10 k\Omega,		1.0	10	dB

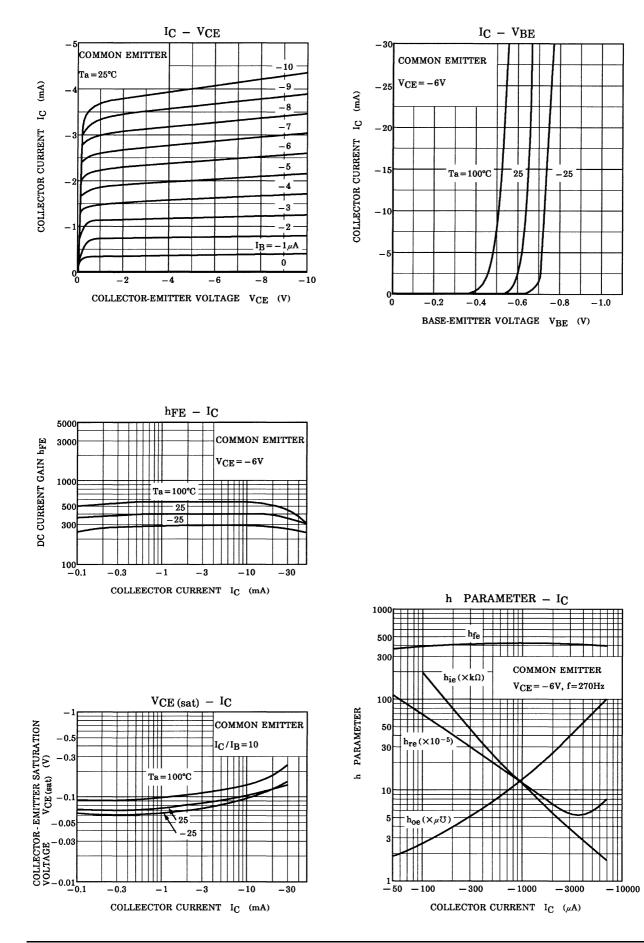
Note: hFE classification GR (G): 200~400, BL (L): 350~700

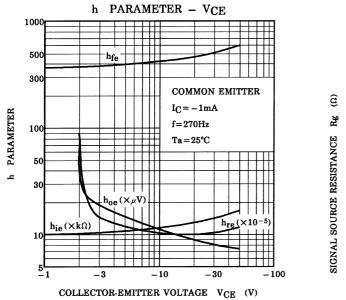
() marking symbol

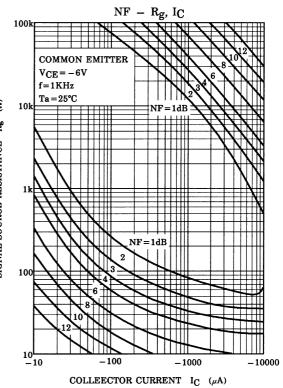
#### Marking

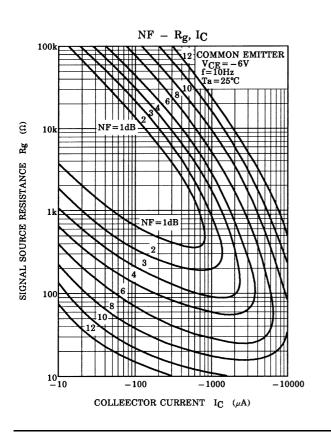


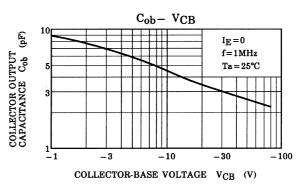
# **TOSHIBA**

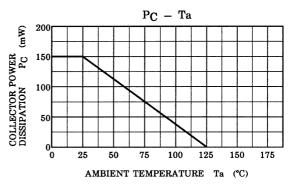












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